Influence of vibrational entropy on the concentrations of oxygen interstitial clusters and uranium vacancies in nonstoichiometric UO₂

Aurélien Soulié,¹ Fabien Bruneval,¹ Mihai-Cosmin Marinica,¹ Samuel Murphy,² and Jean-Paul Crocombette^{1,*}

¹DEN, Service de Recherches de Métallurgie Physique, CEA, Université Paris-Saclay, F-91191 Gif-sur-Yvette, France ²Department of Engineering, Lancaster University, Bailrigg, Lancaster, LA1 4YW, United Kingdom

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We combine density functional theory (DFT) formation energies and empirical potential calculations of vibrational free energies to calculate the free energies of formation of point defects and clusters of oxygen interstitials, and we use a dilute defect model to calculate the concentrations of defects as a function of temperature and composition. We find that at high temperature oxygen interstitials are dominant, either in isolated form or in clusters depending on the deviation from stoichiometry. At temperatures lower than 1300 K we predict uranium vacancies to be dominant in the stoichiometric material. The disorder in UO₂ therefore changes from Schottky to Frenkel type with increasing temperature. Uranium vacancies remain dominant up to deviations form stoichiometry as large as 0.045 at 800 K. Moreover, the concentration of uranium vacancies proves to be non-monotonous as a function of composition. These results are consistent with some experimental data on the evolution with stoichiometry of lattice constant, diffusion coefficients of uranium, positron lifetime and dilatometry measurements.

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I. INTRODUCTION

Uranium oxide is the most widely used nuclear fuel. As such it has been studied extensively both experimentally and numerically. This material exhibits a large domain of composition around its nominal (UO₂) stoichiometry. Deviations from stoichiometry are accommodated by the inclusion of atomic-scale defects in the crystalline fluorite structure. The historical defect model [1,2], dealing only with point defects, assumes that the intrinsic disorder is of the oxygen Frenkel type, i.e., that isolated oxygen vacancies and interstitials are the dominant defects in hypo- and hyperstoichiometric material, respectively. This picture was further complicated by the observation of clusters of oxygen interstitials in UO_{2+x} [3]. However, there is a consensus on the fact that deviations from stoichiometry in UO_2 are accommodated by oxygen defects. Uranium defects, while predicted to exist in the material, are considered minority defects. The main disorder is always explicitly [4,5] or implicitly [6] assumed to be of oxygen Frenkel type.

Many atomistic calculations of the formation energies of defects exist in literature. The earliest density functional theory (DFT) values date back 20 years [7] with many more published since [8–20]. In general, the calculated formation energies appear consistent with experimentally observed defect concentrations. However, when these values are integrated into a dilute defect model (for instance, through a Brouwer diagram), they always predict that uranium vacancies are the most abundant defect in the hyperstoichiometric UO₂ material [8,21]. Calculations, therefore, point to the accommodation of hyperstoichiometry by uranium vacancies, which is direct contradiction

of the dominance of oxygen interstitials in UO_{2+x} . Atomicscale calculations, therefore, face what is widely referred to as the uranium vacancy problem. This shortcoming was observed in early DFT calculations of defect energetics in UO_2 and has resisted the many subsequent improvements of the calculations (increase of the box sizes, introduction of a DFT+U correction, spin-orbit coupling, etc.).

Studies on other materials have shown that the inclusion of vibrational entropy can deeply affect the relative stability of defects in a material [22–26]. Unfortunately, in the UO₂ case, such calculations are impractical at the DFT level because of the tremendous computational burden they represent.

In a recent breakthrough, Cooper et al. [27] combined vibrational calculations performed with empirical potentials with DFT energies to estimate the free energies of formation of defects in UO₂. They showed that because of differences in the vibrational entropies, the uranium vacancies are destabilized at high temperature (larger than about 1200 K) compared to isolated oxygen interstitial defects. Unfortunately, their study dealt only with point defects and did not consider clusters of oxygen interstitials that are known to prevail at large deviations from stoichiometry. Therefore, they were unable to discuss large deviations from stoichiometry and the respective stability of oxygen clusters and uranium vacancies. In the present study, we use the same combination of ab initio energies and vibrational entropies calculated with an empirical potential that enables the description of such clusters. Integrating the free energies of formation of point defects and clusters in a dilute defect model, we are able to predict the concentration of all these defects as a function of stoichiometry. At high temperatures or large deviations from stoichiometry oxygen defects are shown to be dominant. We thus confirm that the uranium vacancy problem disappears when vibrational contributions are included in the calculation of the free energies

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^{*}jpcrocombette@cea.fr

of formation. More importantly our results point to a complex picture of the hyperstoichiometry in UO_{2+x} . Isolated oxygen interstitials, clusters of these and uranium vacancies are shown to dominate in three different regimes of compositions and temperature. Moreover, the concentration of uranium vacancies proves to be nonmonotonous as a function of composition. These unexpected results are proved to be consistent with some available experimental data.

The next part of the paper presents the technicalities of our work, for the *ab initio* and the harmonic calculations and the dilute defect model used to derive the concentrations of defects. The results are then presented and discussed.

II. METHODOLOGY

A. DFT formation energies

We use the formation energies given in our previous publication [21], to which the reader is referred for technical details. In summary, energies were calculated within the DFT theory using the VASP code [28] in the projector augmented wave framework using a GGA+U functional [29] with a matrix control scheme [30,31] to avoid the possible occurrence of local minima. All calculations were done in $2 \times 2 \times 2$ supercells of the conventional unit cell which contains 96 atoms in the perfect crystal.

One obtains the formation energies of the defects from the energy of the simulation boxes with the following formula:

$$\Delta E_{f}^{m,n,q}(\mu_{e}) = E(\mathbf{U}_{32+m}\mathbf{O}_{64+n},q) - \frac{32+m}{32}E(\mathbf{U}_{32}\mathbf{O}_{64}) - \frac{n-2m}{2}E(\mathbf{O}_{2}) + q(\varepsilon_{\text{VBM}} + \mu_{e}) + \Delta E_{\text{Madelung}}.$$
 (1)

In this formula, $E(U_{32}O_{64})$ is the energy of the perfect supercell and $E(U_{32+m}O_{64+n}, q)$ is the energy of the box containing a defect with *m* uranium and *n* oxygen added or removed atoms and charge *q*. μ_e is the electron chemical potential and ε_{VBM} is the energy at the top of the valence band. Finally, $E(O_2)$ is the energy of the oxygen molecule in its triplet ground state.

We have considered the following defects:

-oxygen vacancies V_O , uranium vacancies V_U , oxygen mono interstitials I_O , and three types of oxygen interstitial clusters: I_X^2 , I_X^4 , and I_C^5 made built from 2, 4, and 5 oxygen

interstitials, respectively. For the last defect, charge states were limited from 0 to -4 as higher charge states prove unstable. We also considered the hole and electron polarons explicitly by introducing a U⁵⁺ or U³⁺ ion in the supercell. The values of the energies obtained with Eq. (1) are given in Appendix A of our previous paper [21].

III. SMTB-Q VIBRATIONAL FREE ENERGIES

We calculate the vibrational entropies and the corresponding contributions to the free energies of the defects using the second moment tight binding with charge equilibration (SMTB-Q) empirical potential [32]. This potential includes a second-moment tight-binding formalism for the U-O bonding and a Buckingham term for the O-O bonding. The charges on the atoms are equilibrated with the electronegativity equalization method (EEM) [33]. The parametrization of this potential is the same as in our study on dislocations and plasticity in UO₂ [34]. The ability of the SMTB-Q potential to reproduce the properties of bulk UO_2 is discussed in this previous work. The SMTB-Q potential reproduces accurately the reaction energies for intrinsic Frenkel and Schottky defect processes from experiment and DFT; see Table I. The binding energies of oxygen interstitial clusters are given per oxygen interstitial in the cluster to allow direct comparison of the relative stability of the various clusters. All the defects are taken in their neutral state for this comparison. The last column gives the energy gained when two isolated oxygen interstitials are changed into an additional elementary cell of UO₂ containing a uranium vacancy. The binding energies of DFT and empirical potentials are rather close and point qualitatively to the same trends: energy is gained when isolated interstitials are clustered; I_x^2 are the least stable clusters; the maximum energy gain is obtained when forming a uranium vacancy at the expense of oxygen interstitials. One difference appears for the relative stability of I_X^4 and I_C^5 (i.e., cuboctahedral) clusters. SMTB-Q predicts I_C^5 to be the most stable cluster while DFT calculations predict the opposite consistently with former comparable DFT calculations [13]. Note, however, that the I_X^4 cluster has not been observed experimentally while the cuboctahedral cluster is the building block of the U_4O_9 crystalline structure. We believe there may be an issue in the DFT calculations possibly associated with the limited supercell size, as evidenced by Burr and Cooper [20] for the trivacancy defects in the same material.

TABLE I. Defect end	ergies calculated with	he SMTB-Q potential	, comparison with exp	perimental values,	DFT, and CRG resu	lts
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	Reaction	n energies (eV)	Migration energies (eV)			
Defect	FPo	Schottky Trio	OI	Vo		
SMTB-Q	4.25	5.23	1.02	0.36		
CRG [35]	5.73	10.64				
Exp. [4,5,36–40]	3.0-4.6	6.0-7.0	0.67-1.3	0.38-0.6		
DFT [12,17,18]	2.6-4.2	3.9-6.4	1.14	0.38		
	Per oxygen (eV)					
Binding energies	I_X^2	I_X^4	I_C^5	V_U		
DFT [21]	-0.20	-0.83	-0.78	-0.97		
SMTB-Q	0.01	-0.63	-0.81	-1.64		



FIG. 1. Phonon density of states calculated with SMTB-Q (in red), neutron weighted phonon density of states calculated with SMTB-Q (in blue) compared to experiments extracted from Pang *et al.* [43].

The vibrational contributions to entropy $(S_{vib}^{m,n})$ and free energy $(F_{\text{vib}}^{m,n})$ are calculated in the harmonic approximation [41]. We make use of the phonon dynamics (PHONDY) code developed by Marinica et al. [24,42]. The phonon frequencies of the system are obtained from the diagonalization of the dynamical matrix in $5 \times 5 \times 5$ perfect or defective supercells. The phonon density of states (DOS) for perfect uranium oxide, calculated in $10 \times 10 \times 10$ supercells, is shown in Fig. 1. In this figure one also shows the neutron weighted phonons density of states which is compared to recent inelastic neutron scattering experiments. The calculated neutron-weighted density of states agree reasonably well with experiments, especially for the lowest frequencies which contribute the most to vibrational entropy.

A variable charge potential, based on the EEM principles, cannot reproduce the insulating gap of solids and subsequently cannot distinguish between the different defect charge states. The same entropy is, therefore, attributed to all possible charges for a given defect. The SMTB-Q empirical potential is also unable to describe polaronic defects. We, therefore, neglect the vibrational entropy contribution to the free energy of the polarons.

A. Dilute defect model

From the formation energies [Eq. (1)] and vibrational free energies of the defects one can calculate the formation free energy of a given defect by the following formula:

$$\Delta F_{f}^{m,n,q}(\mu_{e}) = \Delta E_{f}^{m,n,q}(\mu_{e}) + \Delta F_{f-\text{vib}}^{m,n} - \frac{n-2m}{2}F(O_{2}).$$
(2)

In this formula $\Delta F_{f-\mathrm{vib}}^{m,n}$ is the vibrational part of the free energy of formation calculated as

$$\Delta F_{f-\text{vib}}^{m,n} = F_{\text{vib}}^{m,n} - \frac{32+m}{32} F_{\text{vib}}(U_{32}O_{64}).$$
(3)

(one also defines $\Delta S_{f-\mathrm{vib}}^{m,n}$ with an equivalent formula). $F(\mathrm{O}_2)$ is the free energy of the oxygen gas beyond its internal energy term calculated by DFT (see above). It contains a pressure term, and additional terms corresponding to rotational, translational and vibrational entropies. We use the formula by Kröger [44].

The concentration of defect $X_q^{m,n}$ expressed in number of defects per unit cell is then:

$$\left[X_q^{m,n}\right] = M^{n,m} \exp\left(-\frac{\Delta F_f^{m,n,q}(\mu_e)}{k_B T}\right).$$
 (4)

 $M^{n,p}$ is the multiplicity of the defect (m, n) per unit cell. This multiplicity gives the configurational entropy term and is the product of the number of sites in the unit cell and the number of equivalent ways to arrange the atoms to form the defect in each site. At this point the Fermi level remains to be specified. For a given pressure and temperature, it is deduced from the electro-neutrality condition which involves the concentrations of defects and the one of holes and electrons in the valence and conduction bands respectively. One finally obtains, as a function of the oxygen pressure and temperature, the concentration of each defect (including holes, electrons and polarons) and the deviation from stoichiometry x. In the next section we present the results obtained in the hyperstoichiometric regime at various temperatures. We focus on the concentration of the various defects. We also show the variation of the macroscopic length $(\delta L/L)$ of a sample as a function of its stoichiometry which depends on the formation volumes of the defects as:

$$\frac{\delta L}{L} = \frac{1}{3} \left(\sum_{X,q} \left[X_q^{m,n} \right] \frac{V_{X_q^{m,n}}^{\text{rel}}}{V_{\text{u.c.}}} + \sum_{V_{U,q}} [V_{U,q}] \right).$$
(5)

In this equation, $V_{u.c.}$ is the volume of the unit cell of UO₂ and the $V_{X_q}^{\text{rel}}$ are the relaxation volumes of the defects, i.e., the variation of the supercell volume upon introduction of the defect. The calculation of these volumes is a nontrivial task as raw pressures obtained in *ab initio* calculations are meaningless for charged cells [45]. In Eq. (5) the first term of the right-hand side if the variation of the unit cell of the material $(\delta a/a)$ and the second term corresponds to the variation of the number of unit cell induced by the creation of uranium vacancies. Indeed, we consider equilibrium between UO2 and an oxygen gas, introducing a uranium vacancy requires the creation of an additional unit cell of UO₂.

IV. RESULTS

The values of $\Delta F_{f-\text{vib}}^{m,n}$ for the point defects are given in Table II for various temperatures.

TABLE II. Vibrational contribution to the free energy of formation of defects $\Delta F_{f-vib}^{m,n}$ (eV) calculated with the SMTB-Q potential [see Eq. (3)].

	V_O	I_O	I_X^2	I_X^4	I_C^5	V_U
400 K	-0.11	-0.14	-0.31	-0.60	-0.54	-0.08
700 K	-0.08	-0.35	-0.75	-1.47	-1.48	-0.02
1000 K	-0.02	-0.60	-1.26	-2.48	-2.59	0.08
1300 K	0.07	-0.87	-1.81	-3.57	-3.81	0.19
1600 K	0.17	-1.16	-2.40	-4.75	-5.14	0.32
1900 K	0.29	-1.46	-3.02	-5.97	-6.51	0.47



FIG. 2. Formation entropy of hyperstoichiometric defects from SMTB-Q calculations. The entropy $\Delta S_{f-\text{vib}}^{m,n}$ are divided by the number of oxygen interstitials they contain or amount to.

Figure 2 shows the formation entropy of hyperstoichiometric defects divided by the number of oxygen interstitials they amount to. One then observes that the formation entropy of the clusters of oxygen interstitials are close to each other while the entropy of uranium vacancies is about $4k_B$ per O_I smaller at all temperatures. This indicates that oxygen interstitials will be favored over uranium vacancies, especially at high temperature where the contribution of entropy to the formation free energy is important.

We now describe the results obtained with the dilute model for the concentrations of defects. In the hypostoichiometric regime (UO_{2-x} , not shown), as expected, the deviation from stoichiometry is accommodated by oxygen vacancies. For the stoichiometric material (Fig. 3), at temperatures lower than 1300 K we predict uranium vacancies to be dominant. For larger temperatures, isolated interstitials take over and become dominant. In the hyperstoichiometric material, one can note that the nature of the dominant defect changes with temperature and stoichiometry (Fig. 3). At low temperatures (e.g., 700 K), uranium vacancies are dominating at all deviations from stoichiometry. At these temperatures, entropy contributions are small, and one finds the same results as in the calculations with DFT energies only [16,21]. With increasing temperature, the uranium vacancies become destabilized relative to oxygen interstitials. Around 1000 K uranium vacancies still dominate at small x while interstitials clusters take over above x = 0.02. At 1300 K oxygen mono-interstitials and uranium vacancies appear to coexist with comparable concentrations while clusters become rapidly dominant (at x larger than 0.01). Finally, at 1600 K, the hyperstoichiometry is accommodated by mono interstitials and interstitial clusters. One can note the nonmonotonous evolution of the concentration of uranium vacancies: except at 700 K where they always dominate, their



FIG. 3. Concentrations of defects as a function of x in UO_{2+x} for different temperatures. Note that uranium vacancies (respectively, oxygen interstitials) are dominant at low (respectively, high) temperatures. For clarity, we only report the total concentration for each defect where all the possible charge states have been summed up.



FIG. 4. Dominant defect as a function of temperature and deviation from stoichiometry (*x*) in UO_{2+x} ; The shaded area indicates the miscibility gap [46] between UO_2 and U_4O_9 (inaccessible compositions).

concentration increases with x close to perfect stoichiometry then decreases with x at large hyperstoichiometry.

V. DISCUSSION

Our calculations confirm the results of Copper *et al.* [27]. Dealing only with point defects, they have shown that including the vibrational free energies of defects stabilizes the oxygen mono-interstitials respective to the uranium vacancies. We obtain qualitatively close results when restricting our defect database of energy and entropy values to point defects only (O_i, V_O, V_U) . It is interesting to note that uranium oxide has long been presented as the prototype of Frenkel disorder (with a majority of V_O and O_I) material. Our calculations contradict this too simple picture and suggest that the nature of the disorder in UO_2 changes from Schottky (with a majority of V_U and V_O) to Frenkel type with increasing temperature.

The inclusion of clusters of oxygen interstitials allows us to explore large deviations from stoichiometry. One then obtains that clusters become dominant at large deviations from stoichiometry for all temperatures. Our results on UO_{2+x} can be summarized with a diagram indicating which defect is dominant as a function of temperature and stoichiometry (see Fig. 4). In this figure, not all compositions are accessible. Indeed, the domain of existence of UO_{2+x} is limited at low temperatures: a miscibility gap appears between U_4O_9 and UO_{2+x} at temperatures lower than 1400 K. This phase limit cannot be obtained from our modeling which describes only UO_{2+x} . We resorted to the thermodynamical Calphad modeling of Guenau et al. [46] to draw the miscibility gap indicated by a shaded area in 4. For x and T in this area the thermodynamically stable material is a mixture of U₄O₉ and less hyperstoichiometric UO₂.

At high temperature, our results show that oxygen interstitials dominate in their isolated form at small hyperstoichiometries, while clusters predominate far from perfect stoichiometry. The change from isolated to clustered interstitials takes place at increasing values of x with rising tem-



FIG. 5. Elongation of UO_{2+x} relative to stoichiometric UO_2 as a function of x for different temperatures.

perature. This is expected as high temperature favors isolated defects over clusters because of configurational entropy.

Results at lower temperature are more surprising. They indicate a rather large domain of temperature and compositions where uranium vacancies dominate. Even if this domain is restricted by the limit of existence of the UO_{2+x} phase, we predict uranium vacancies to be the majority defects at temperatures as high as 1300 K and for deviations from stoichiometry as large as 0.045 around 800 K. This prediction contradicts the widely accepted picture of the defect chemistry of UO_{2+x} . It is indeed commonly thought that hyperstoichiometry is always accommodated by oxygen interstitials. The experimental facts underlying this assertion are the observed higher density of U_4O_9 compared to UO_2 [47,48] and the neutron observations of clusters of oxygen interstitials [49]. In the latter Willis compares the absolute Bragg intensities of UO_2 and U_4O_9 and states that "there is no evidence for the formation of uranium vacancies on oxidation. The uranium sublattice remains intact between UO_{2.00} and UO_{2.25}, and oxidation proceeds by the incorporation of additional oxygen atoms at interstitial sites in the fluorite cell." It is worth noting however that these experiments were performed either in the two-phase region of the phase diagram where one in fact has a mixture of UO_{2+x} and U₄O₉ phases or at high temperature. They do not contradict our suggestion of the occurrence of a region at low temperature and small deviations from stoichiometry where uranium vacancies are the dominant defects.

Moreover, there is at least one experiment clearly supporting the existence of uranium vacancies in UO_{2+x} . Desgranges *et al.* [50] measured the expansion of a single crystal as a function of $p(O_2)$ at 1473 K by dilatometry experiments and found that UO_{2+x} first expands at low oxygen pressure (low *x*) then contracts at large pressure (i.e., large hyperstoichiometry). A similar behavior is found at intermediate temperatures in our calculations. Figure 5 shows the elongation of UO_{2+x} as a function of *x* at various temperatures obtained from Eq. (5). This expansion then contraction is a clear sign of a large concentration of uranium vacancies in slightly hyperstoichiometric UO_2 . Unfortunately, Desgranges *et al.* results are difficult to compare quantitatively with our results as their samples contained a large amount of impurities thus blurring the $p(O_2)$ -x relationship in their experiments [51]. We believe it would be interesting to perform additional experiments of this kind to check our prediction about uranium vacancies being the dominant defect in UO_{2+x} at low and intermediate temperatures (below 1200 K) and moderate deviations from stoichiometry.

Another unexpected result from our simulations appears in the high temperature regime when oxygen clusters are dominant. Far from stoichiometry one can observe that concentration of uranium vacancies is decreasing. Simple arguments would suggest that the larger the deviation from stoichiometry is, the larger the concentration of uranium vacancies should be. This is in fact not the case because of the charge of these vacancies and of the evolution of the Fermi level. Hyperstoichiometric defects, such as the dominant oxygen interstitials clusters have negative to neutral charges. As their concentrations increases, more and more hole polarons appear in the material to compensate their charge. This induces a decrease of the Fermi level which is shifted toward the valence band (more precisely toward the polaronic defect level in the gap). Charge transition levels of the uranium vacancies are such that they always have their formal charge (-4) whatever the position of the Fermi level in the gap. Decreasing the Fermi level thus induces an increase of their formation energy [see Eq. (1)], which in turn leads to a decrease in their concentration. Some experimental observations tend to confirm this nonmonotonous evolution of the uranium vacancy concentrations.

First positron lifetime measurements carried out by Yue [52] for four well-controlled compositions (x =0.002, 0.042, 0.16, 0.21) showed an increase then a decrease of the lifetime of positrons (167, 265, 256, 171 ps) as a function of x. Positron lifetimes relate monotonously to the concentration of vacancies in a material. In UO_{2+x} only uranium vacancies are significant, therefore, one can then deduce qualitatively from these experiments that the concentration of uranium vacancies increases then decreases with increasing hyperstoichiometry, as predicted in our calculations. Second, another hint of a possible decrease of the concentration of uranium vacancies at large x is given by the self-diffusion coefficients of uranium in hyperstoichiometric uranium oxide which is mediated by uranium vacancies. The measured diffusion coefficient scales as the product of the vacancy concentration by the jump frequency of each vacancy. Experimentally, one observes a general increase of the diffusion coefficient with the deviation from stoichiometry. However, at least one experiment by Hawkins et al. [53] shows a final drop of the diffusion at the largest measured hyperstoichiometries for two temperatures. Assuming a constant jump frequency, such a reduction points to a final decrease of the concentrations of uranium vacancies

in largely hyperstoichiometric oxide, in qualitative agreement with our calculations.

Both these experiments are thus consistent with a decrease of the concentration of uranium vacancies at large deviations from stoichiometry. They point however to a larger value of x for the maximum amount of uranium vacancies, somewhere around x = 0.1 when we predict a maximum for around 0.01. This difference may seem large, but it corresponds in the Brouwer diagram to a quite moderate change in the chemical potential of oxygen of only 0.3 eV or equivalently one order of magnitude in the oxygen pressure.

Additional experimental confirmation of the nonmonotonous evolution with stoichiometry of the concentration of uranium vacancies would validate our calculations as a whole and thus the prediction of a (temperature-stoichiometry) regime where uranium vacancies are dominant.

VI. CONCLUSIONS

Our calculations exhibit a change in the nature of disorder in UO2 from Schottky to Frenkel type with increasing temperature. They also point to a quite complex accommodation of hyperstoichiometry in UO_{2+x} . At low deviations from stoichiometry isolated interstitials are the dominant defect. Conversely, large deviations from stoichiometry are accommodated by clusters of oxygen interstitials. However, strikingly, at temperatures lower than 1300 K we predict uranium vacancies to be dominant up to deviations form stoichiometry as large as 0.045 at 800 K. The actual existence of such majority uranium vacancies may be hampered by the much slower diffusivity of uranium compared to oxygen so that the true thermodynamic equilibrium may be difficult to observe for kinetic reasons. However, some experimental observations indicate that uranium vacancies may be present in nonnegligible concentrations in hyperstoichiometric UO₂ and that the predicted non-monotonous evolution of their concentration may be observed experimentally. We hope this simulation work will stimulate further experiments, possibly dilatometry or diffusion measurements, to assess the actual concentration of uranium vacancies in moderately hyperstoichiometric uranium oxide at intermediate temperatures.

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